www.ti.com

SGLS312J-SEPTEMBER 2005-REVISED JUNE 2011

AUTOMOTIVE LOW-DROPOUT VOLTAGE REGULATORS

Check for Samples: TL750Mxx-Q1, TL751Mxx-Q1

FEATURES

- Qualified for Automotive Applications
- Low Dropout Voltage, Less Than 0.6 V at 750 mA
- Low Quiescent Current
- TTL- and CMOS-Compatible Enable on TL751M Series
- Load-Dump Protection
- Overvoltage Protection
- Internal Thermal Overload Protection
- Internal Overcurrent-Limiting Circuitry

DESCRIPTION

The TL750M and TL751M series are low-dropout positive voltage regulators specifically designed for automotive applications. The TL750M and TL751M series incorporate onboard overvoltage and current-limiting protection circuitry to protect the devices and the regulated system. Both series are fully protected against load-dump and reverse-battery conditions. Load-dump protection is up to a maximum of 60 V at the input of the device. Low quiescent current, even during full-load conditions, makes the TL750M and TL751M series ideal for use in applications that are permanently connected to the vehicle battery.

The TL750M and TL751M series offers 5-V, 8-V, and 12-V options. The TL751M series has the addition of an enable (ENABLE) input. The ENABLE input gives complete control over power up, allowing sequential power up or shutdown. When ENABLE is high, the regulator output is placed in the high-impedance state. The ENABLE input is TTL and CMOS compatible.

The TL750Mxx and TL751Mxx are characterized for operation over the virtual junction temperature range –40°C to 125°C.

AVAILABLE OPTIONS(1)

TJ	V _O NOM (V)	PACKA	SE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	5 V	TO-263-3 – KTT	Reel of 500	TL750M05QKTTRQ1	TL750M05Q1
	3 V	TO-252-3 – KVU	Reel of 2500	TL750M05QKVURQ1	750M05Q
	8 V	TO-263-3 – KTT	Reel of 500	TL750M08QKTTRQ1	TL750M08Q1
	0 V	TO-252-3 – KVU	Reel of 2500	TL750M08QKVURQ1	750M08Q
	12 V	TO-263-3 – KTT	Reel of 500	TL750M12QKTTRQ1	TL750M12Q1
–40°C to 125°C		TO-252-3 – KVU	Reel of 2500	TL750M12QKVURQ1	750M12Q
-40 C to 125 C	5 V	TO-263-5 – KTT	Reel of 500	TL751M05QKTTRQ1	TL751M05Q1
		TO-252-5 – KVU	Reel of 2500	TL751M05QKVURQ1	751M05Q
		TO-263-5 – KTT	Reel of 500	TL751M08QKTTRQ1	TL751M08Q1
	8 V	TO-252-5 – KVU	Reel of 2500	TL751M08QKVURQ1	751M08Q
	12 V	TO-263-5 – KTT	Reel of 500	TL751M12QKTTRQ1	TL751M12Q1
	I∠ V	TO-252-5 – KVU	Reel of 2500	TL751M12QKVURQ1	751M12Q

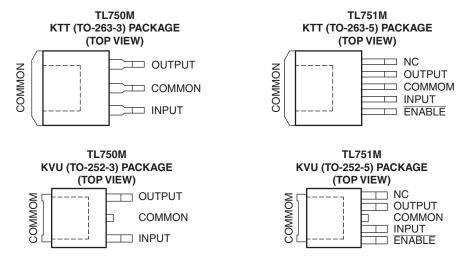
⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

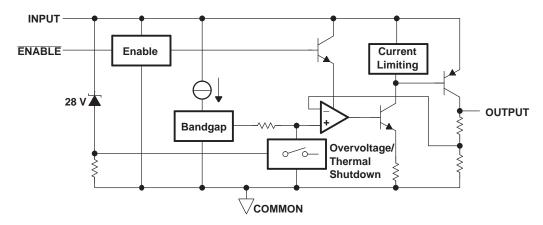
⁽²⁾ Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.





NOTE: The COMMON terminal is in electrical contact with the mounting base. NC – No internal connection

TL751Mxx FUNCTIONAL BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

	Continuous input voltage		26 V
	Transient input voltage (see Figure 4)		60 V
	Continuous reverse input voltage	–15 V	
	Transient reverse input voltage	t = 100 ms	–50 V
		KTT package (3 pin)	26.9°C/W
θ_{JA}	Package thermal impedance (2) (3)	KTT package (5 pin)	26.5°C/W
		KVU package	38.6°C/W
T_{J}	Virtual junction temperature range	ction temperature range	
T _{stg}	Storage temperature range	−65°C to 150°C	

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_J(max) T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can impact reliability. Due to variation in individual device electrical characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.
- (3) The package thermal impedance is calculated in accordance with JESD 51.

THERMAL INFORMATION

		TL750M05	
	THERMAL METRIC ⁽¹⁾	КТТ	UNITS
		3 PINS	
θ_{JA}	Junction-to-ambient thermal resistance ⁽²⁾	27.5	
θ_{JCtop}	Junction-to-case (top) thermal resistance (3)	43.2	
θ_{JB}	Junction-to-board thermal resistance (4)	17.3	°C // //
ΨЈТ	Junction-to-top characterization parameter ⁽⁵⁾	2.8	°C/W
ΨЈВ	Junction-to-board characterization parameter ⁽⁶⁾	9.3	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance ⁽⁷⁾	0.3	

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
		TL75xM05	6	26	
V_{I}	Input voltage	TL75xM08	9	26	V
		TL75xM12	13	26	
V _{IH}	High-level ENABLE input voltage	TL751Mxx	2	15	V
V_{IL}	Low-level ENABLE input voltage	TL751Mxx	0	0.8	V
Io	Output current	TL75xMxx		750	mA
T_J	Operating virtual junction temperature	TL75xMxx	-40	125	°C



TL751Mxx ELECTRICAL CHARACTERISTICS

 $V_I = 14 \text{ V}, I_O = 300 \text{ mA}, T_J = 25^{\circ}\text{C}$

PARAMETER	TL751Mxx	UNIT
PARAMETER	TYP	UNIT
Response time, ENABLE to output (start-up)	50	μs

TL750M05/TL751M05 ELECTRICAL CHARACTERISTICS

 $V_I = 14 \text{ V}$, $I_O = 300 \text{ mA}$, ENABLE at 0 V for TL751M05, $T_J = -40^{\circ}\text{C}$ to 125°C (unless otherwise noted)⁽¹⁾

PARAMETER	TEST CONDITIONS	TL750M05 TL751M05	UNIT
		MIN TYP MA	X
Output voltage	V _I = 6 V to 26 V	4.85 5 5.	15 V
Line regulation	$V_I = 9 \text{ V to } 16 \text{ V}, \qquad I_O = 250 \text{ mA}$	10	25
Line regulation	$V_I = 6 \text{ V to } 26 \text{ V}, \qquad I_O = 250 \text{ mA}$	12	mV
Power-supply ripple rejection	$V_1 = 8 \text{ V to } 18 \text{ V}, \qquad f = 120 \text{ Hz}$	55	dB
Load regulation	I _O = 5 mA to 750 mA	20	50 mV
Dropout voltage (2)	$I_{O} = 500 \text{ mA}, T_{J} = 25^{\circ}\text{C}$	(.5 V
Dropout voltage —	$I_O = 750 \text{ mA}, T_J = 25^{\circ}\text{C}$	0.	
Current consumption	I _O = 750 mA	60	75
$I_{q} = I_{I} - I_{O}$	I _O = 10 mA		mA 5
Shutdown current (TL751M05 only)	ENABLE V _{IH} ≥ 2 V	2	00 μΑ

¹⁾ Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 4.

TL750M08/TL751M08 ELECTRICAL CHARACTERISTICS

 $V_I = 14 \text{ V}$, $I_O = 300 \text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V for TL751M08, $T_J = -40^{\circ}\text{C}$ to 125°C (unless otherwise noted)⁽¹⁾

PARAMETER	TEST CONDITIONS	TL750M08 TL751M08			
		MIN TYP	MAX		
Output voltage	V _I = 6 V to 26 V	7.76 8	8.24	V	
Line regulation	$V_I = 10 \text{ V to } 17 \text{ V}, \qquad I_O = 250 \text{ mA}$	12	40	m\/	
Line regulation	$V_1 = 9 \text{ V to } 26 \text{ V}, \qquad I_0 = 250 \text{ mA}$	15	68	mV	
Power-supply ripple rejection	$V_1 = 11 \text{ V to } 21 \text{ V}, \qquad f = 120 \text{ Hz}$	55		dB	
Load regulation	I _O = 5 mA to 750 mA	24	80	mV	
Dropout voltage (2)	I _O = 500 mA, T _J = 25°C		0.5	V	
Dropout voltage 7	$I_O = 750 \text{ mA}, T_J = 25^{\circ}\text{C}$		V		
Current consumption	$I_{O} = 750 \text{ mA}, T_{J} = 25^{\circ}\text{C}$	60	75	A	
$I_{q} = I_{I} - I_{O}$	I _O = 10 mA		mA		
Shutdown current (TL751M08 only)	ENABLE V _{IH} ≥ 2 V		200	μΑ	

⁽¹⁾ Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 4.

⁽²⁾ Measured when the output voltage, V_0 , has dropped 100 mV from the nominal value obtained at $V_1 = 14$ V.

⁽²⁾ Measured when the output voltage, V_0 , has dropped 100 mV from the nominal value obtained at $V_1 = 14$ V.



TL750M12/TL751M12 ELECTRICAL CHARACTERISTICS

 $V_1 = 14 \text{ V}$, $I_0 = 300 \text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V for TL751M12, $T_1 = -40^{\circ}\text{C}$ to 125°C (unless otherwise noted)⁽¹⁾

PARAMETER	TEST CONDITIONS	1	TL750M12 TL751M12			
		MIN	TYP	MAX		
Output voltage	V _I = 13 V to 26 V	11.76	12	12.24	V	
Line regulation	$V_I = 14 \text{ V to } 19 \text{ V}, \qquad I_O = 250 \text{ mA}$		15	43	m\/	
Line regulation	$V_{I} = 13 \text{ V to } 26 \text{ V}, \qquad I_{O} = 250 \text{ mA}$		20	78	mV	
Power-supply ripple rejection	V _I = 13 V to 23 V, f = 120 Hz	50	55		dB	
Load regulation	$I_O = 5$ mA to 750 mA		30	120	mV	
Dropout voltage ⁽²⁾	$I_{O} = 500 \text{ mA}, T_{J} = 25^{\circ}\text{C}$			0.5	V	
Dropout voltage (=/	$I_O = 750 \text{ mA}, T_J = 25^{\circ}\text{C}$			0.6	V	
Current consumption	$I_{O} = 750 \text{ mA}, T_{J} = 25^{\circ}\text{C}$		60	75	A	
$I_q = I_l - I_O$	I _O = 10 mA				mA	
Shutdown current (TL751M12 only)	ENABLE V _{IH} ≥ 2 V			200	μA	

⁽¹⁾ Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-µF capacitor across the input and a 10-µF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 4. Measured when the output voltage, V_O , has dropped 100 mV from the nominal value obtained at V_I = 14 V.



PARAMETER MEASUREMENT INFORMATION

The TL750Mxx and TL751Mxx are low-dropout regulators. The output capacitor value and the parasitic equivalent series resistance (ESR) affect the bandwidth and stability of the control loop for these devices. For this reason, the capacitor and ESR must be carefully selected for a given operating temperature and load range. Figure 2 and Figure 3 can be used to establish the appropriate capacitance value and ESR for the best regulator transient response.

Figure 2 shows the recommended range of ESR for a given load with a 10- μ F capacitor on the output. Figure 2 also shows a maximum ESR limit of 2 Ω and a load-dependent minimum ESR limit.

For applications with varying loads, the lightest load condition should be chosen because it is the worst case. Figure 3 shows the relationship of the reciprocal of ESR to the square root of the capacitance, with a minimum capacitance limit of 10 μ F and a maximum ESR limit of 2 Ω . This figure establishes the amount that the minimum ESR limit shown in Figure 2 can be adjusted for different capacitor values. For example, where the minimum load needed is 200 mA, Figure 2 suggests an ESR range of 0.8 Ω to 2 Ω for 10 μ F. Figure 3 shows that changing the capacitor from 10 μ F to 400 μ F can change the ESR minimum by greater than 3/0.5 (or 6). Therefore, the new minimum ESR value is 0.8/6 (or 0.13 Ω). This allows an ESR range of 0.13 Ω to 2 Ω , achieving an expanded ESR range by using a larger capacitor at the output. For better stability in low-current applications, a small resistance placed in series with the capacitor (see Table 1) is recommended, so that ESRs better approximate those shown in Figure 2 and Figure 3.

Table 1. Compensation for Increased Stability at Low Currents

MANUFACTURER	CAPACITANCE	ESR TYP	PART NUMBER	ADDITIONAL RESISTANCE
AVX	15 µF	0.9 Ω	TAJB156M010S	1 Ω
KEMET	33 µF	0.6 Ω	T491D336M010AS	0.5 Ω

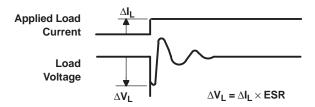


Figure 1.



OUTPUT CAPACITOR EQUIVALENT SERIES RESISTANCE (ESR) vs LOAD CURRENT RANGE

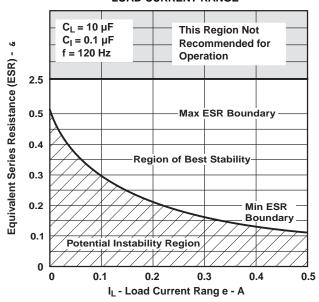


Figure 2.

STABILITY vs EQUIVALENT SERIES RESISTANCE (ESR)

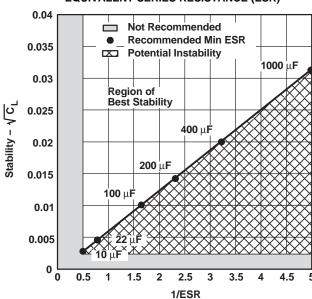


Figure 3.



TYPICAL CHARACTERISTICS

Table 2. Table of Graphs

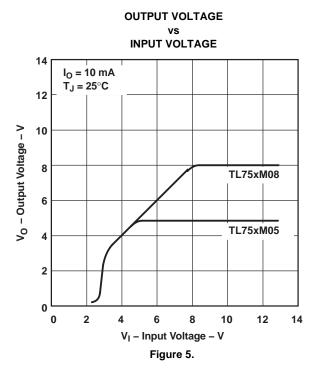
			FIGURE
Transient input voltage	vs Time		4
Output voltage	vs Input voltage	vs Input voltage	
Innut ourrent	vo lanut voltago	I _O = 10 mA	6
Input current	vs Input voltage	$I_0 = 100 \text{ mA}$	7
Dropout voltage	vs Output current	vs Output current	
Quiescent current	vs Output current		9
Load transient response	10		
Line transient response	11		

TIME 60 $T_J = 25^{\circ}C$ V_{I} = 14 V + 46e^(-t/0.230) for t \geq 5 ms 50 V_I - Transient Input Voltage - V 40 30 t_r = 1 ms 20 10 0 100 200 300 400 500 600

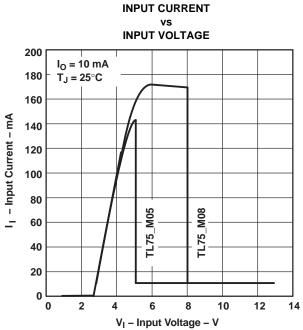
t - Time - ms

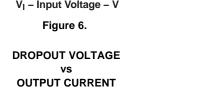
Figure 4.

TRANSIENT INPUT VOLTAGE









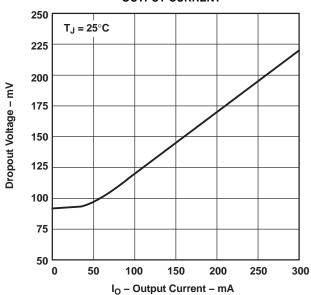
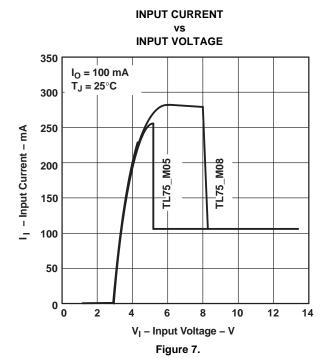
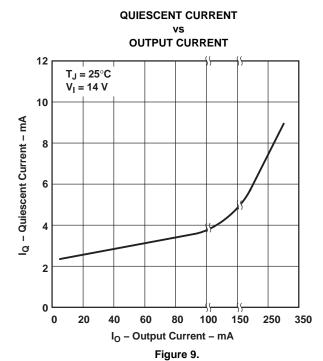
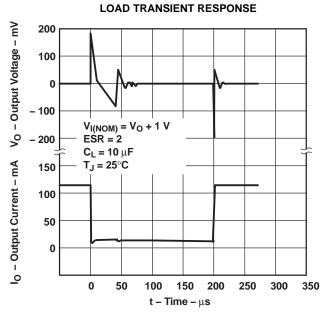


Figure 8.











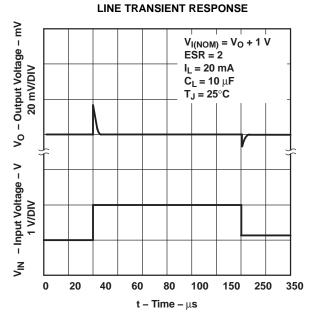


Figure 11.

www.ti.com

11-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TL750M05QKTTRQ1	Active	Production	DDPAK/ TO-263 (KTT) 3	500 SMALL T&R	Yes	SN	Level-3-245C-168 HR	-40 to 125	TL750M05Q1
TL750M05QKTTRQ1.A	Active	Production	DDPAK/ TO-263 (KTT) 3	500 SMALL T&R	Yes	SN	Level-3-245C-168 HR	-40 to 125	TL750M05Q1
TL750M05QKVURQ1	Active	Production	TO-252 (KVU) 3	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	750M05Q
TL750M05QKVURQ1.A	Active	Production	TO-252 (KVU) 3	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	750M05Q
TL750M08QKVURQ1	Active	Production	TO-252 (KVU) 3	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	750M08Q
TL750M08QKVURQ1.A	Active	Production	TO-252 (KVU) 3	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	750M08Q
TL750M12QKTTRQ1	Active	Production	DDPAK/ TO-263 (KTT) 3	500 LARGE T&R	Yes	SN	Level-3-245C-168 HR	-40 to 125	TL750M12Q1
TL750M12QKTTRQ1.A	Active	Production	DDPAK/ TO-263 (KTT) 3	500 LARGE T&R	Yes	SN	Level-3-245C-168 HR	-40 to 125	TL750M12Q1
TL750M12QKVURQ1	Active	Production	TO-252 (KVU) 3	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	750M12Q
TL750M12QKVURQ1.A	Active	Production	TO-252 (KVU) 3	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	750M12Q
TL751M05QKVURQ1	Active	Production	TO-252 (KVU) 5	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	751M05Q
TL751M05QKVURQ1.A	Active	Production	TO-252 (KVU) 5	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	751M05Q
TL751M08QKTTRQ1	Active	Production	DDPAK/ TO-263 (KTT) 5	500 LARGE T&R	Yes	SN	Level-3-245C-168 HR	-40 to 125	TL751M08Q1
TL751M08QKTTRQ1.A	Active	Production	DDPAK/ TO-263 (KTT) 5	500 LARGE T&R	Yes	SN	Level-3-245C-168 HR	-40 to 125	TL751M08Q1
TL751M08QKVURQ1	Active	Production	TO-252 (KVU) 5	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	751M08Q
TL751M08QKVURQ1.A	Active	Production	TO-252 (KVU) 5	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	751M08Q
TL751M12QKTTRQ1	Active	Production	DDPAK/ TO-263 (KTT) 5	500 LARGE T&R	Yes	SN	Level-3-245C-168 HR	-40 to 125	TL751M12Q1
TL751M12QKTTRQ1.A	Active	Production	DDPAK/ TO-263 (KTT) 5	500 LARGE T&R	Yes	SN	Level-3-245C-168 HR	-40 to 125	TL751M12Q1
TL751M12QKVURQ1	Active	Production	TO-252 (KVU) 5	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	751M12Q
TL751M12QKVURQ1.A	Active	Production	TO-252 (KVU) 5	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	751M12Q

⁽¹⁾ Status: For more details on status, see our product life cycle.

PACKAGE OPTION ADDENDUM

www.ti.com 11-Nov-2025

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TL750M-Q1:

Catalog: TL750M

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 24-Apr-2020

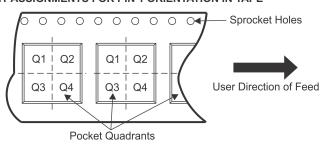
TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO P1 BO W Cavity AO

	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

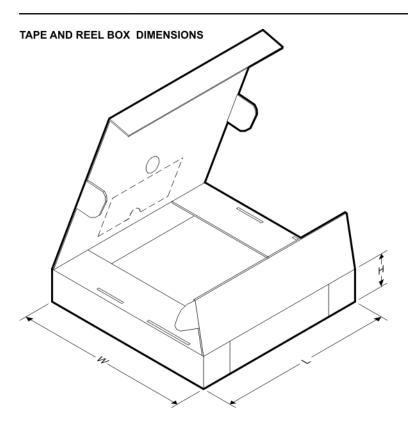
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

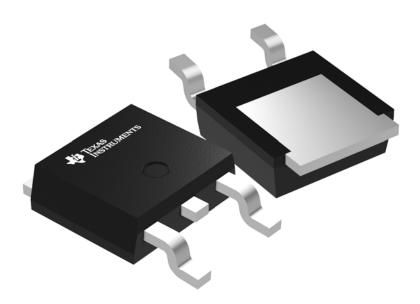
^All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL750M05QKVURQ1	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
TL750M08QKVURQ1	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
TL750M12QKTTRQ1	DDPAK/ TO-263	KTT	3	500	330.0	24.4	10.6	15.8	4.9	16.0	24.0	Q2
TL750M12QKVURQ1	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
TL751M05QKVURQ1	TO-252	KVU	5	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
TL751M08QKTTRQ1	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.6	15.8	4.9	16.0	24.0	Q2
TL751M08QKVURQ1	TO-252	KVU	5	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
TL751M12QKTTRQ1	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.6	15.8	4.9	16.0	24.0	Q2
TL751M12QKVURQ1	TO-252	KVU	5	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2

www.ti.com 24-Apr-2020



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL750M05QKVURQ1	TO-252	KVU	3	2500	340.0	340.0	38.0
TL750M08QKVURQ1	TO-252	KVU	3	2500	340.0	340.0	38.0
TL750M12QKTTRQ1	DDPAK/TO-263	KTT	3	500	340.0	340.0	38.0
TL750M12QKVURQ1	TO-252	KVU	3	2500	340.0	340.0	38.0
TL751M05QKVURQ1	TO-252	KVU	5	2500	340.0	340.0	38.0
TL751M08QKTTRQ1	DDPAK/TO-263	KTT	5	500	340.0	340.0	38.0
TL751M08QKVURQ1	TO-252	KVU	5	2500	340.0	340.0	38.0
TL751M12QKTTRQ1	DDPAK/TO-263	KTT	5	500	340.0	340.0	38.0
TL751M12QKVURQ1	TO-252	KVU	5	2500	340.0	340.0	38.0



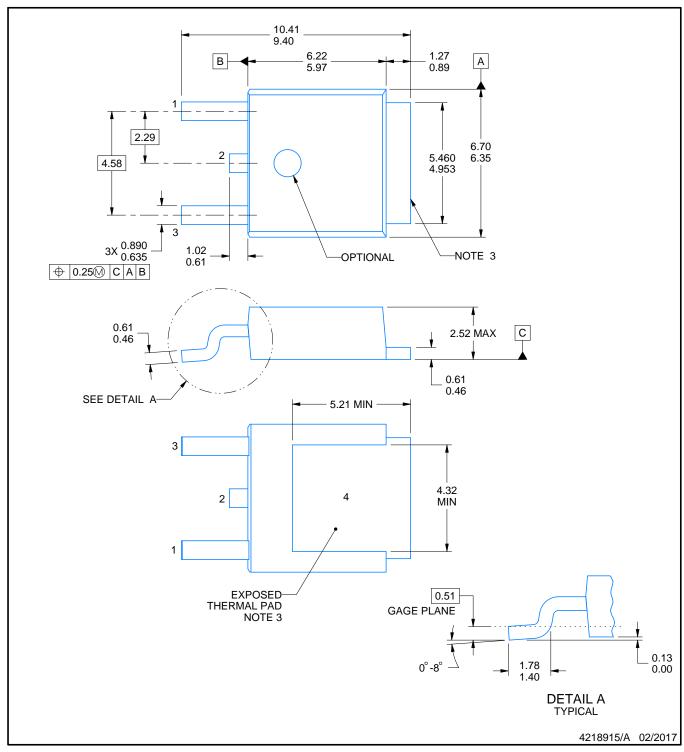
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4205521-2/E





TO-252



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

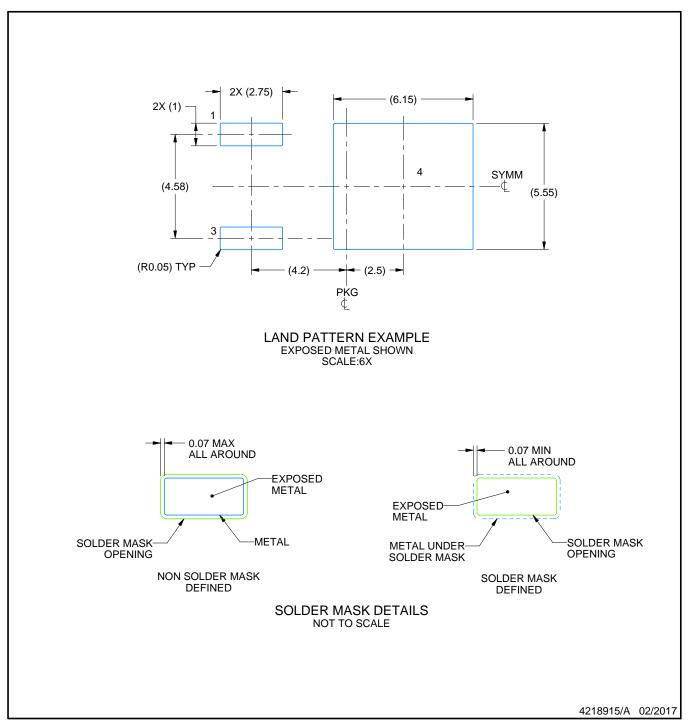
 2. This drawing is subject to change without notice.

 3. Shape may vary per different assembly sites.

 4. Reference JEDEC registration TO-252.



TO-252

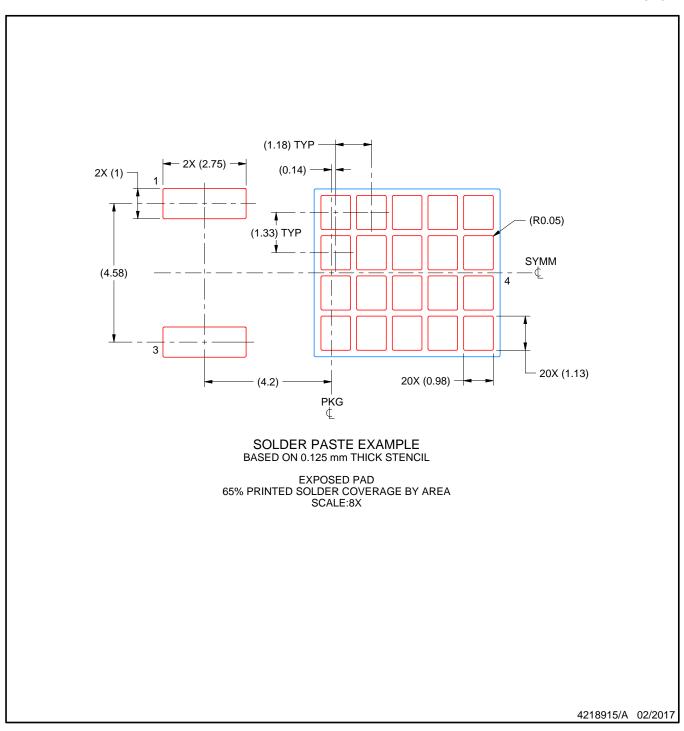


NOTES: (continued)

- 5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).
- 6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.



TO-252



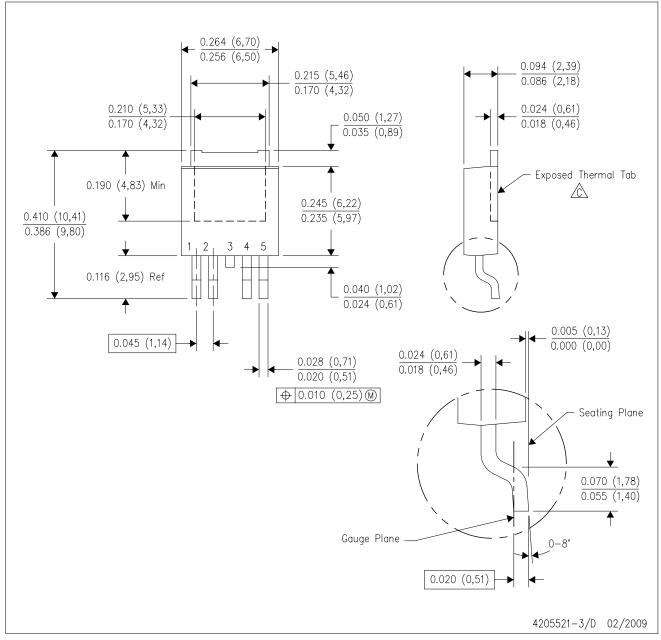
NOTES: (continued)



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations

design recommendations.

8. Board assembly site may have different recommendations for stencil design.

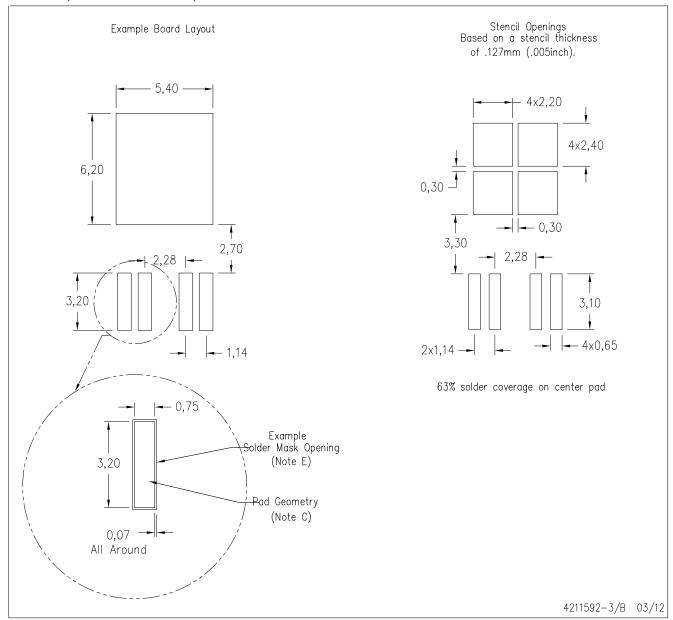


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- The center lead is in electrical contact with the exposed thermal tab.
- D. Body Dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.006 (0,15) per side.
- E. Falls within JEDEC TO-252 variation AD.



KVU (R-PSFM-G5)

PLASTIC FLANGE MOUNT PACKAGE

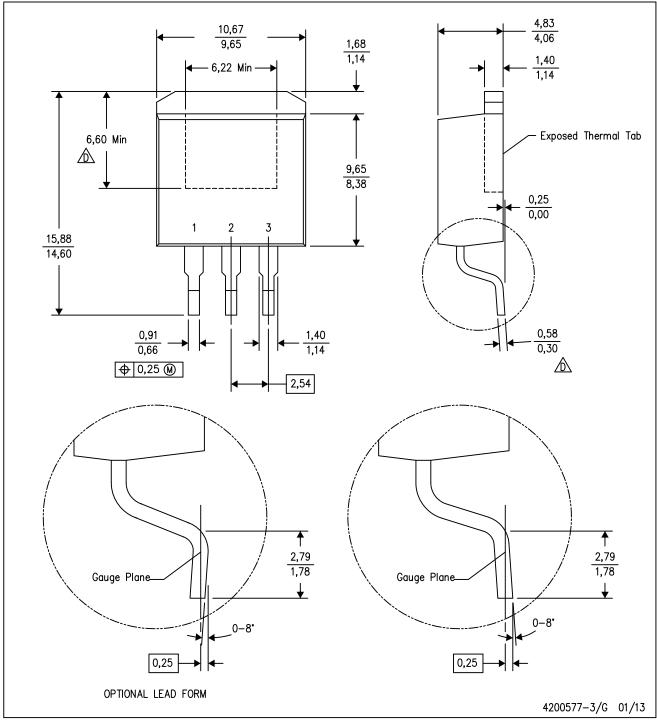


- A. All linear dimensions are in millimeters.
- 3. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is an alternate information source for PCB land pattern designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in thermal pad.



KTT (R-PSFM-G3)

PLASTIC FLANGE-MOUNT PACKAGE

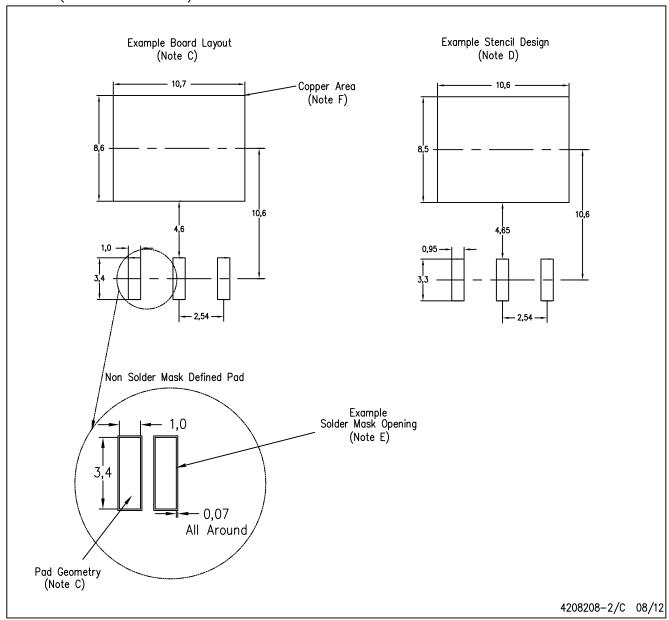


- A. All linear dimensions are in millimeters.
- 3. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 (0,13) per side.
- ⚠ Falls within JEDEC T0—263 variation AA, except minimum lead thickness and minimum exposed pad length.



KTT (R-PSFM-G3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES: A.

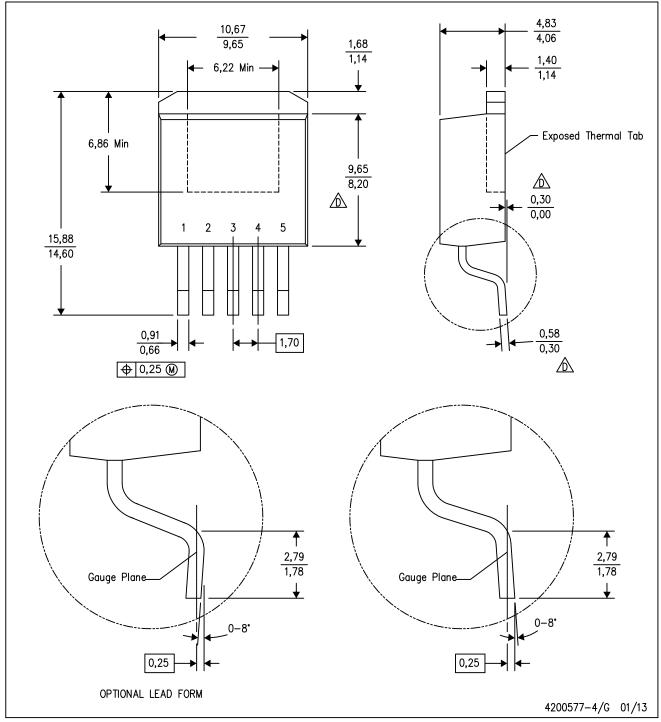
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.

 Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
- F. This package is designed to be soldered to a thermal pad on the board. Refer to the Product Datasheet for specific thermal information, via requirements, and recommended thermal pad size. For thermal pad sizes larger than shown a solder mask defined pad is recommended in order to maintain the solderable pad geometry while increasing copper area.



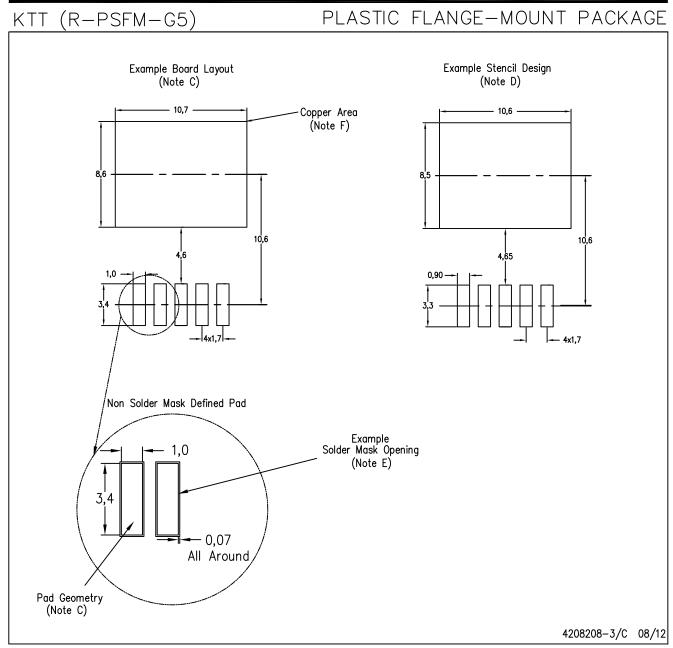
KTT (R-PSFM-G5)

PLASTIC FLANGE-MOUNT PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 (0,13) per side.
- Falls within JEDEC T0—263 variation BA, except minimum lead thickness, maximum seating height, and minimum body length.





NOTES: A.

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.

 Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
- F. This package is designed to be soldered to a thermal pad on the board. Refer to the Product Datasheet for specific thermal information, via requirements, and recommended thermal pad size. For thermal pad sizes larger than shown a solder mask defined pad is recommended in order to maintain the solderable pad geometry while increasing copper area.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale, TI's General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025